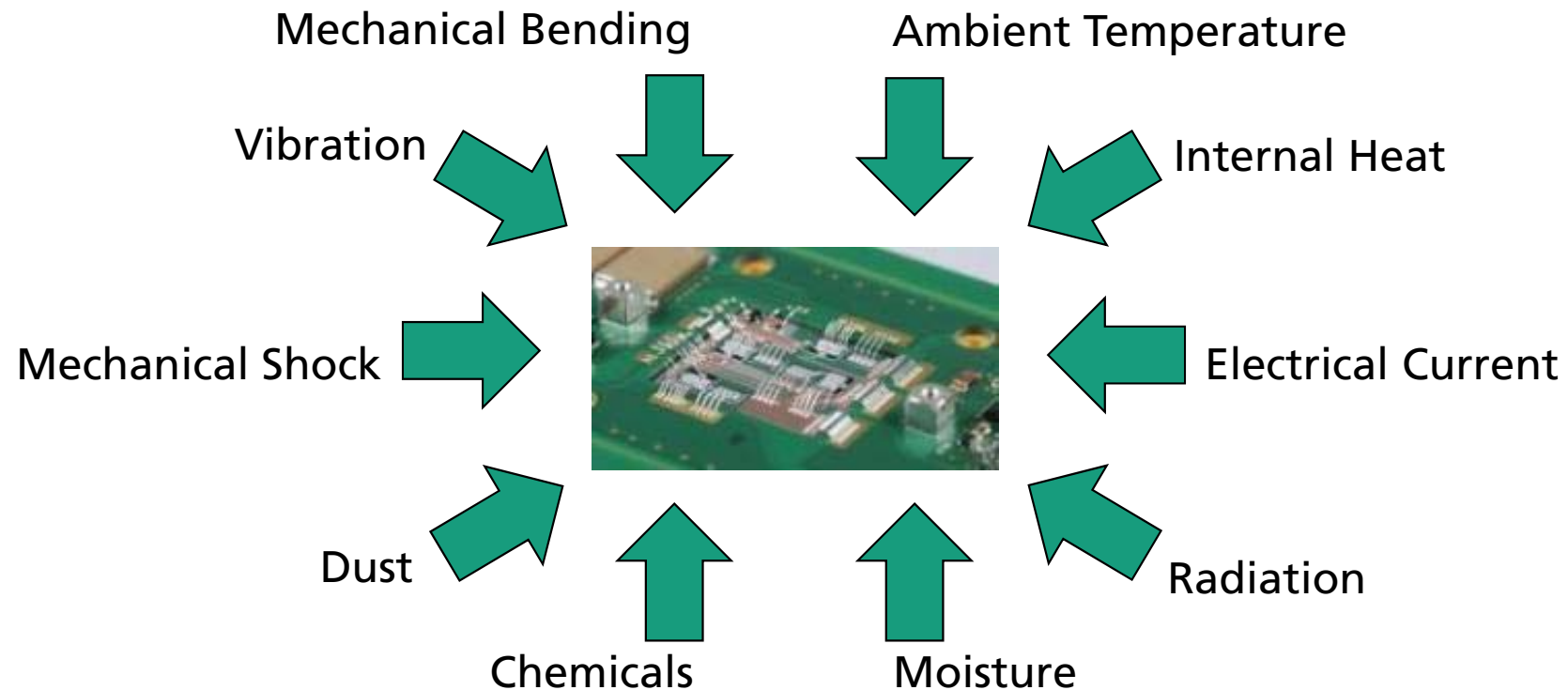


# Combined Loads and Mechanisms

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Fraunhofer IZM Berlin, \*) TU Berlin



# Combined Loads and Mechanisms

## Contents

- Introduction
  - Load Profiles
  - Modelling Approach
- Test Approach for Wire Bond
  - Active Thermal Cycling
  - Temperature Control
  - Damage Monitoring
- Life Time Model for Wire Bond
  - Damage Parameter
  - Calibration
- Summary & Outlook

# INTRODUCTION

02.12.2014

Wittler et al.

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# Complex Use Profiles for Power Modules

- There is a combination of passive und aktive thermal cycles in use conditions (i.e. E-Mobility, Windenergy)
- Passive ones are due to the environment
- Active ones are due to self-heating

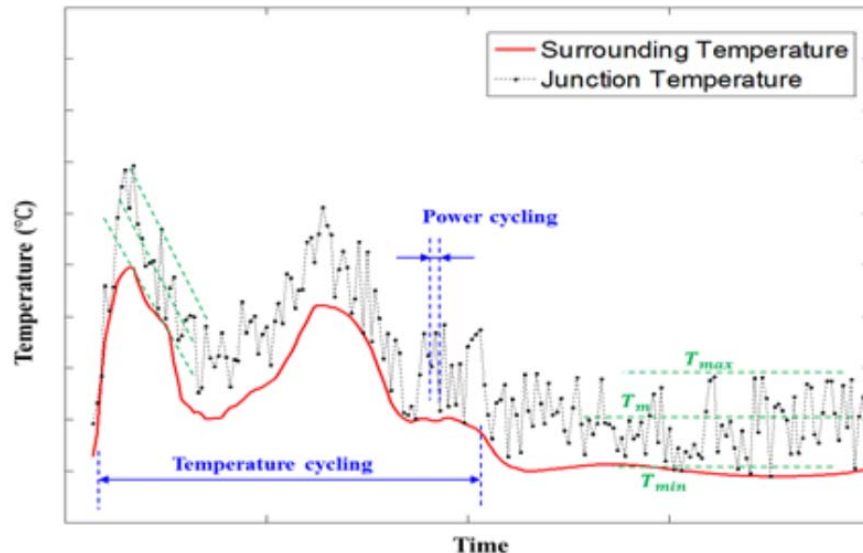


Fig. 2. Thermal cycling and Power cycling for IGBT module

*Multi-Objective Design of IGBT Power Modules Considering Power Cycling and Thermal Cycling, Bing Ji et al.*

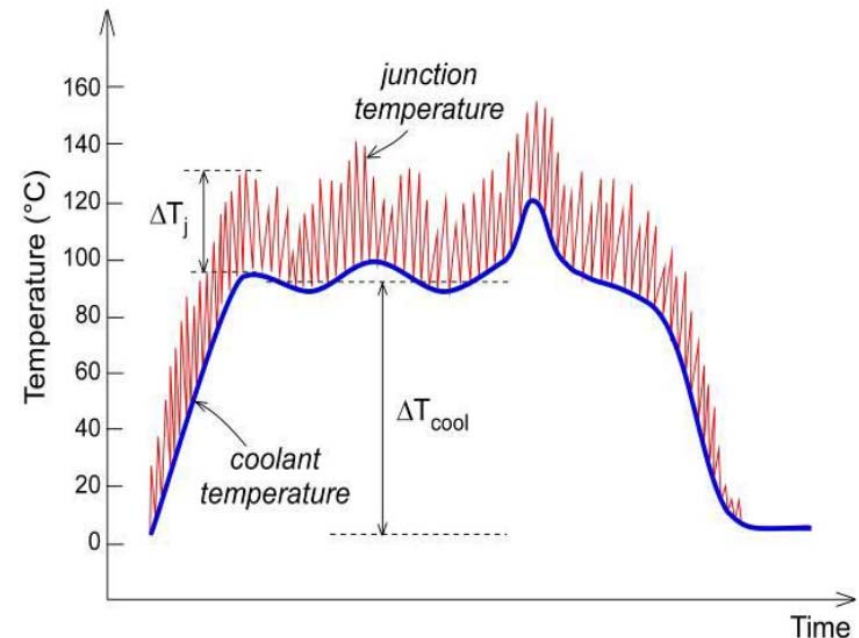


Fig.1 : Typical thermal and power cycling in automotive environment

*Comparison of stress distributions and failure modes during thermal cycling and power cycling on high power IGBT modules, M. Bouarroudja et al.*

# Sate of the Art Evaluation

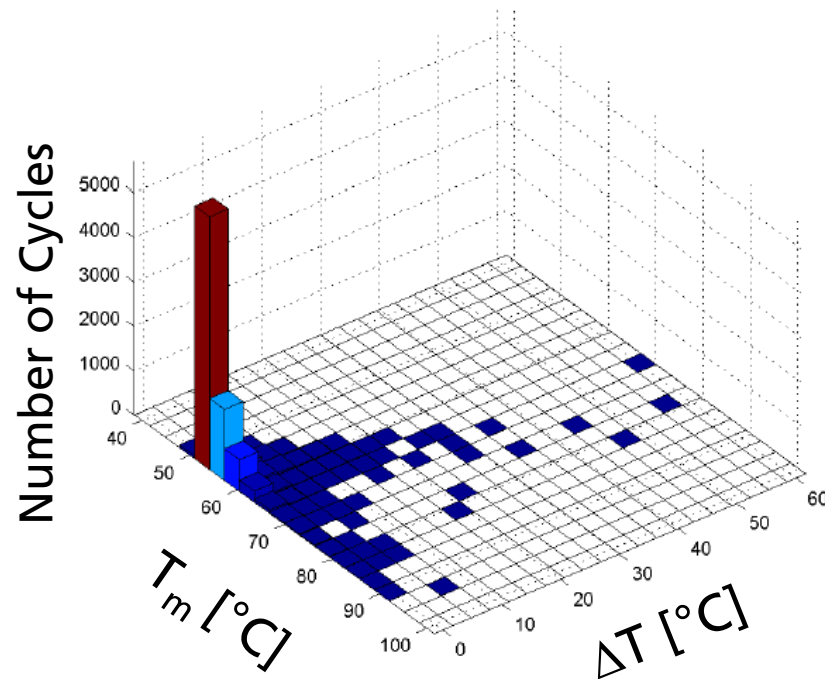


Figure 4.12: Cycles found in the IGBT chip temperature in the wind turbine within a 24 hour period.

- Application of Miner's Rule (Linear Damage Superposition)
- Application of Lifetime Models combining module lifetime in one simplified model:

$$N_f = A \cdot (\Delta T_j)^\alpha \cdot e^{\left(\frac{E_a}{k_B \cdot T_m}\right)}$$

Source: POWER CYCLING LIFETIME ESTIMATION OF IGBT POWER MODULES BASED ON CHIP TEMPERATURE MODELING, Mika Ikonen

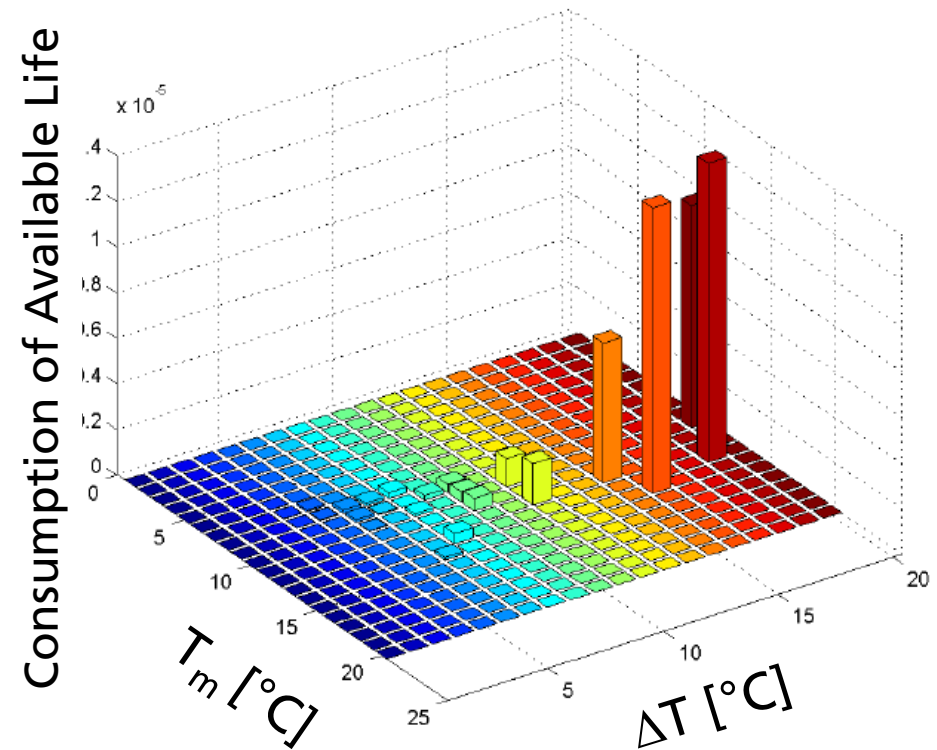
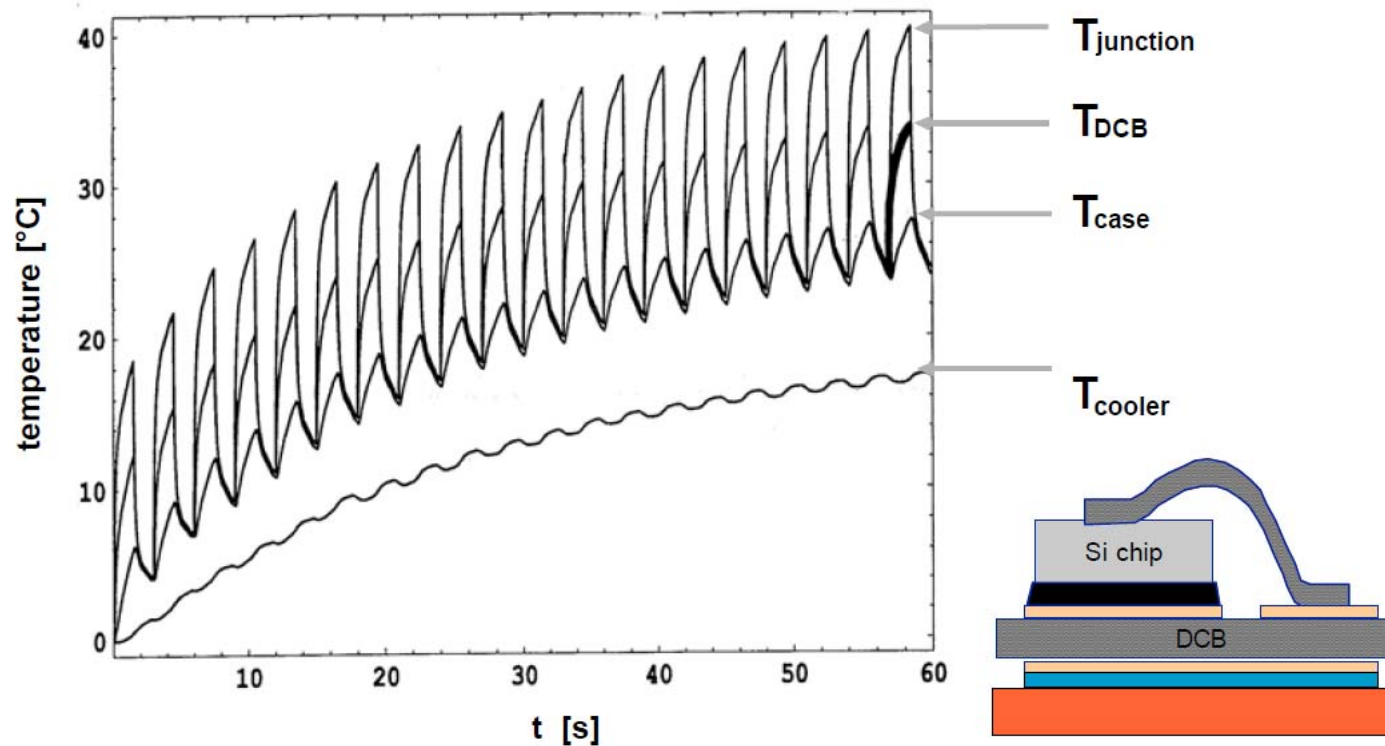


Figure 4.13: Consumption of available life in percents for each bin.

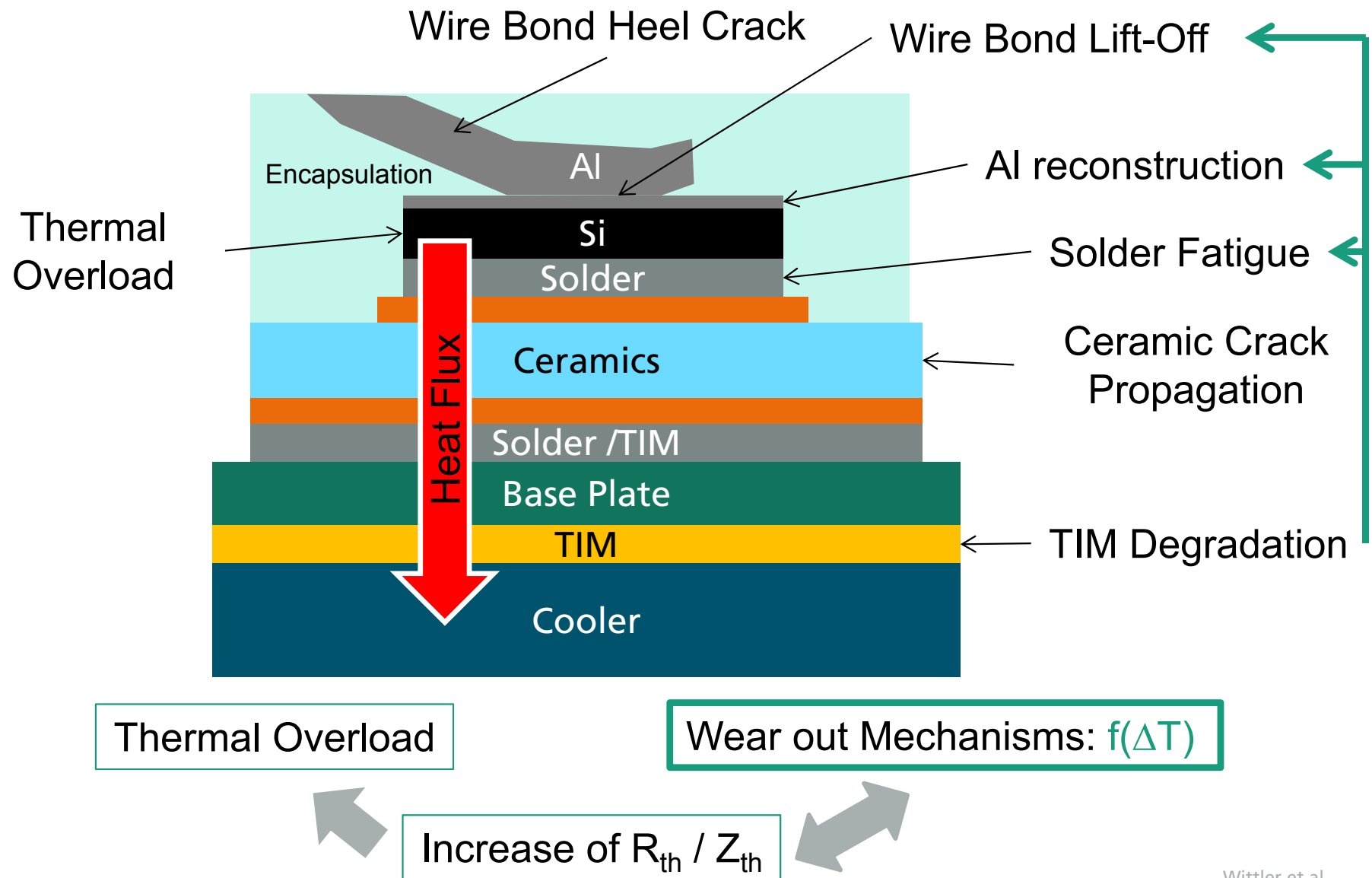
# Motivation

- Active cycles (short time constant) cause a varying  $\Delta T$  inside the module
- Passive cycles (large time constant) cause a general off-sett
- Therefore they have a different effect



AN-Number: AN2003-x04, eupec

# Typical Failure Mechanisms in Power Electronics



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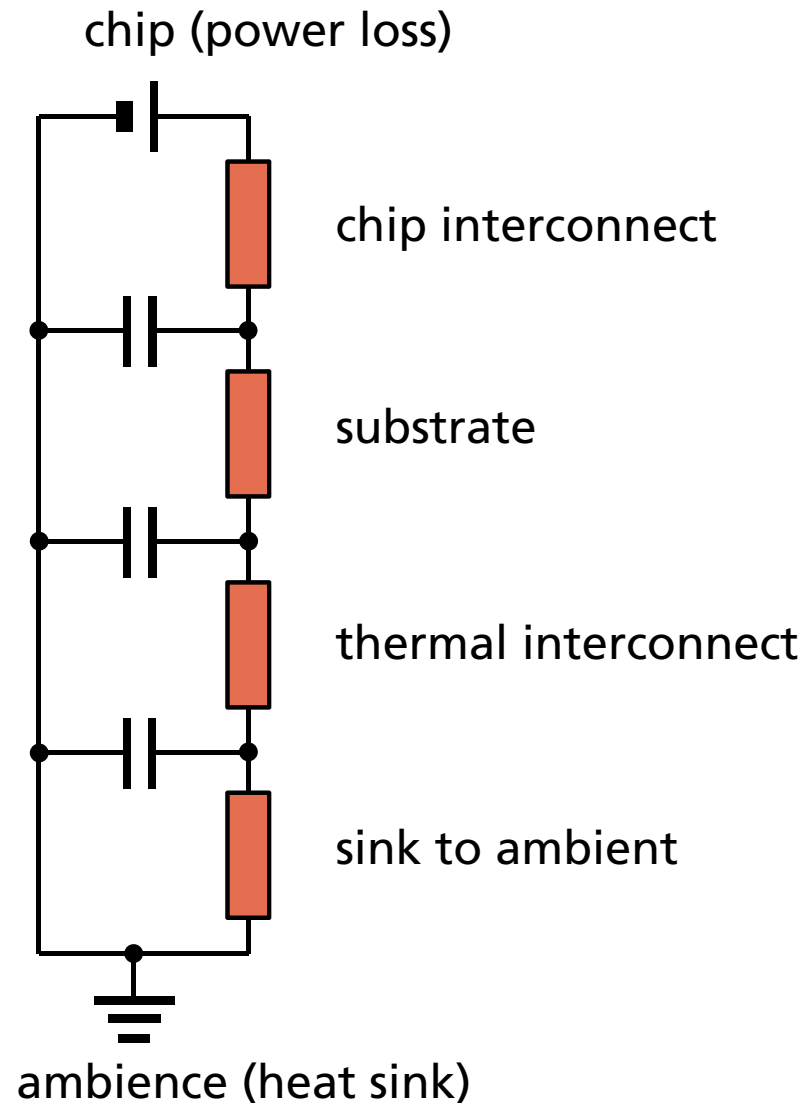
Wittler et al.

# Conclusion on State of the Art

- Complex load histories (i.e. active and passive cycling) are highly relevant in power electronic applications.
  - Current state-of-the-art lifetime models neglect the existing **interaction of failure mechanisms** and **nonlinearity in damage superposition**.
  - A prediction of life time for complex load histories is not possible
- Large safety margins or improved lifetime models needed



# Thermal and Combined Damage Model

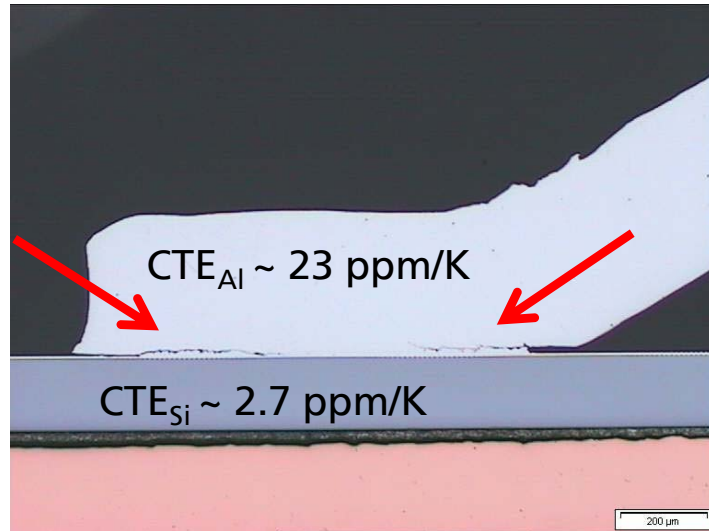


- Power loss and thermal resistance directly depend on the current temperature cycle
$$P = P(T_{cyc}), R = R(T_{cyc})$$
- Damage also increases thermal resistances due to material degradation and/or interface reduction
$$R = R(D)$$
- The damage progression again a function of temperature
$$\dot{D} = D(T_{cyc})$$
- The calculation is done for each thermal cycle, so that ongoing damage is considered

# Requirements for Damage Parameter D

- Can be attributed to a specific failure mechanism
- Is being described based on the local temperature history
- Is being described by a lifetime model

→ Quantification **damage vs. local temperature load** in model and experiment



# TEST APPROACH FOR WIRE BOND

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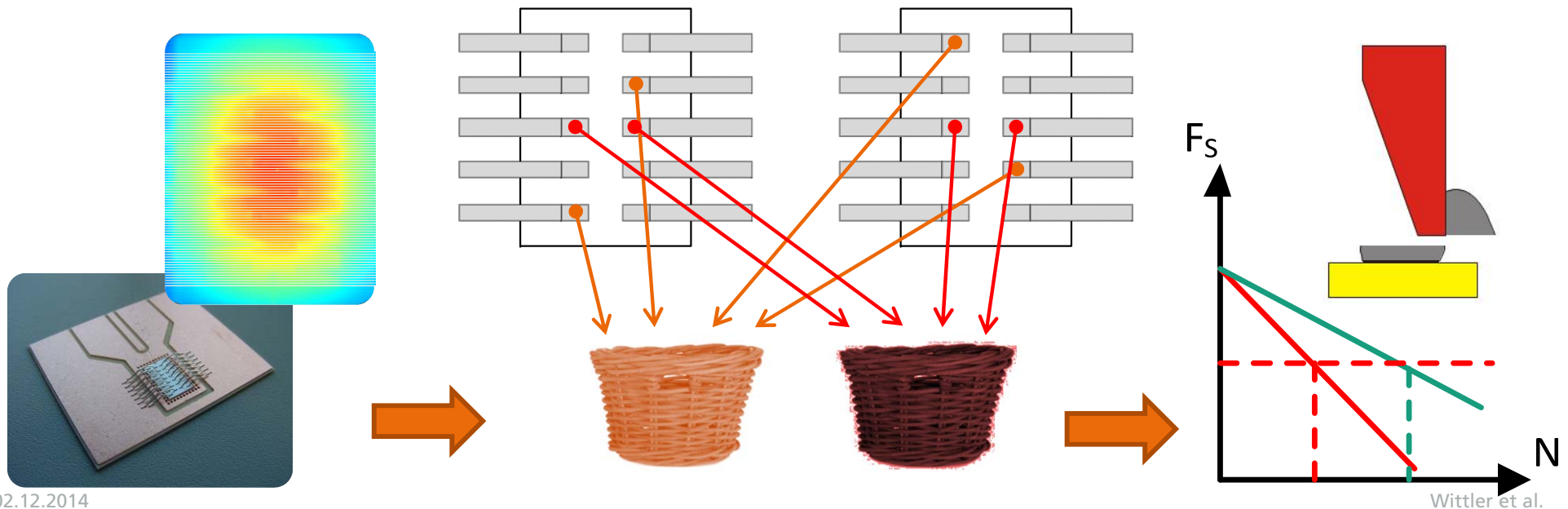
Wittler et al.

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# Reliability Investigations

- Bonding Parameter Optimization
- Active Power Cycling
- Constant temperature swing  $-20/+100^{\circ}\text{C}$  ( $\Delta T = 120\text{K}$ , center of chip)
- Thermography
- Extraktion of local temperature swing for each bond
- Classification of bonds by their temperature swing ( $\pm 2,5\text{K}$ )
- Shear testing in regular intervals



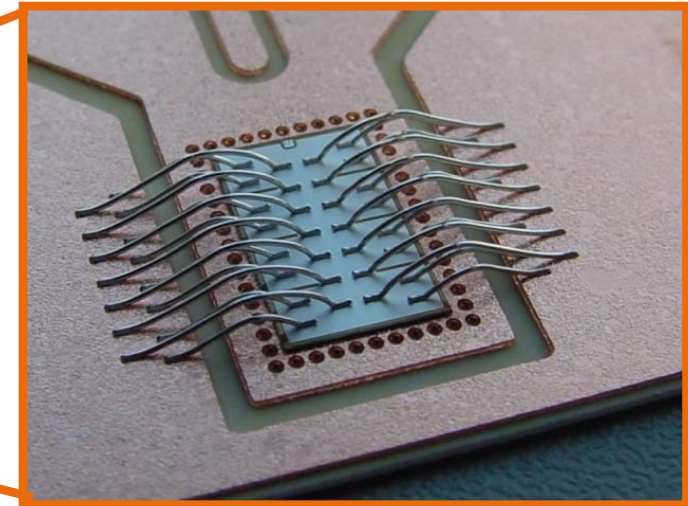
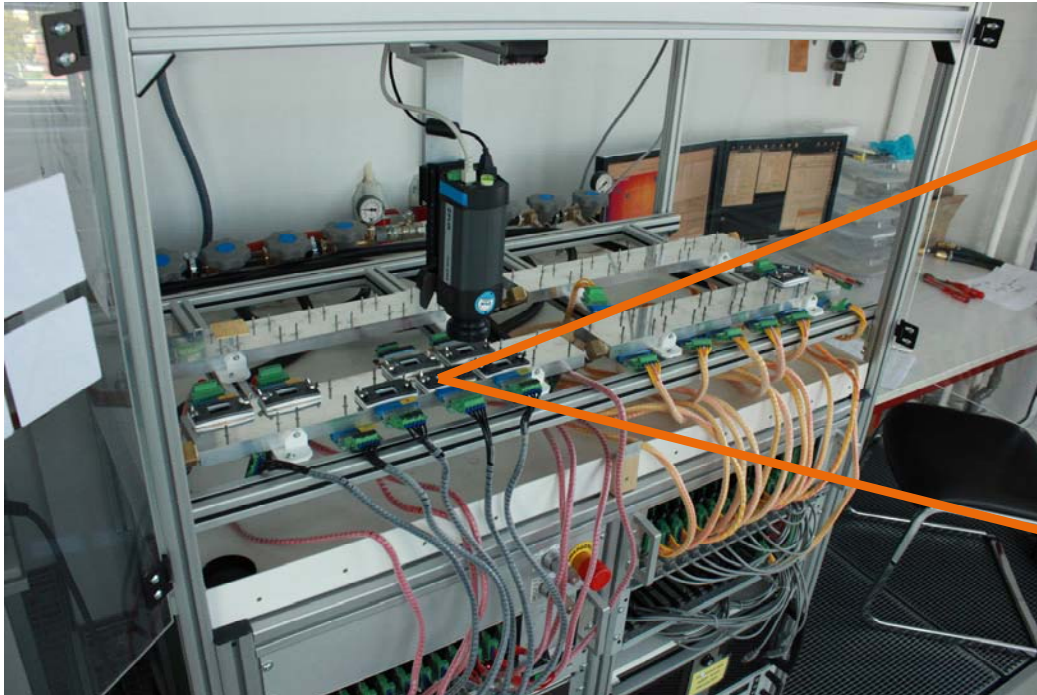
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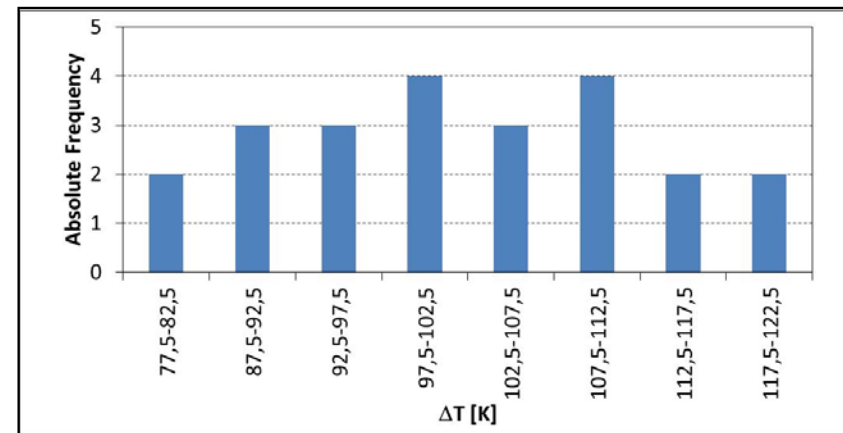
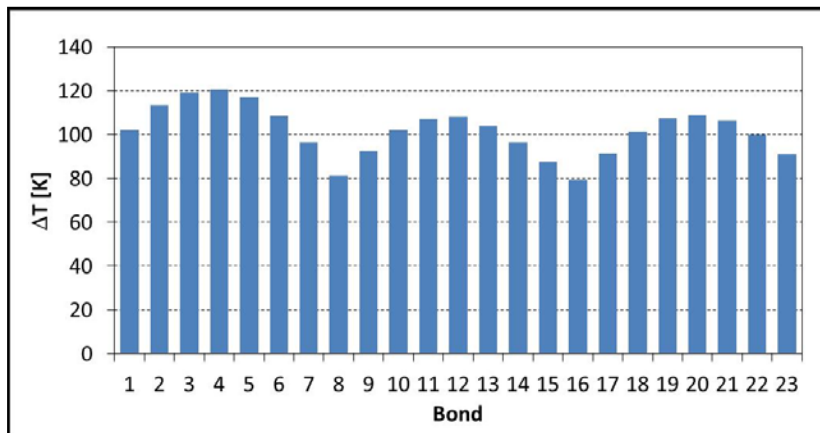
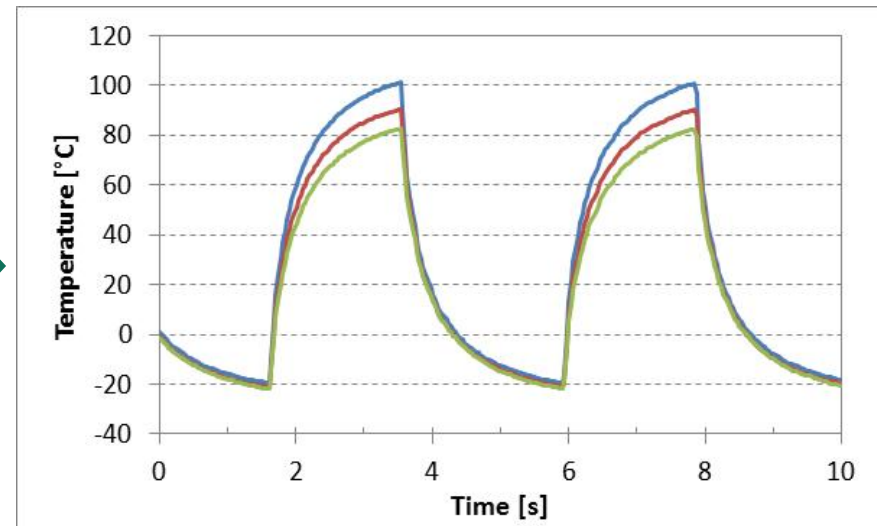
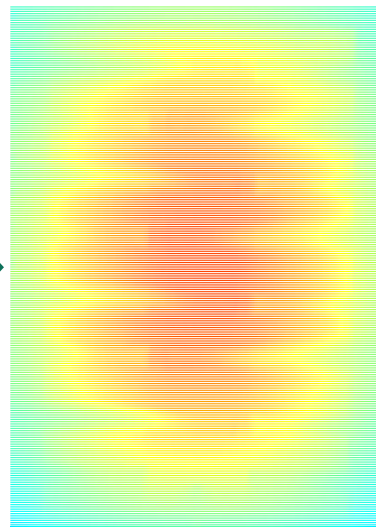
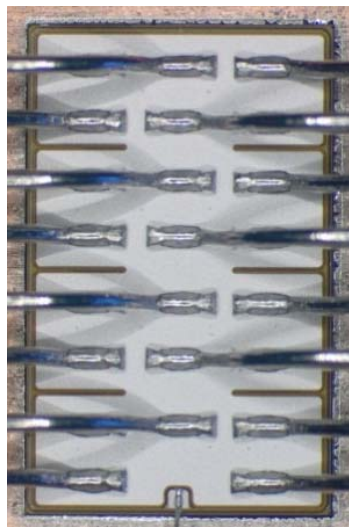
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# Active Power Cycling



- Regular temperature measurement by use of reverse diode in MOSFET
- Control for constant temperature swing by use of control of gate source voltage

# Temperature Distribution on Power Semiconductor

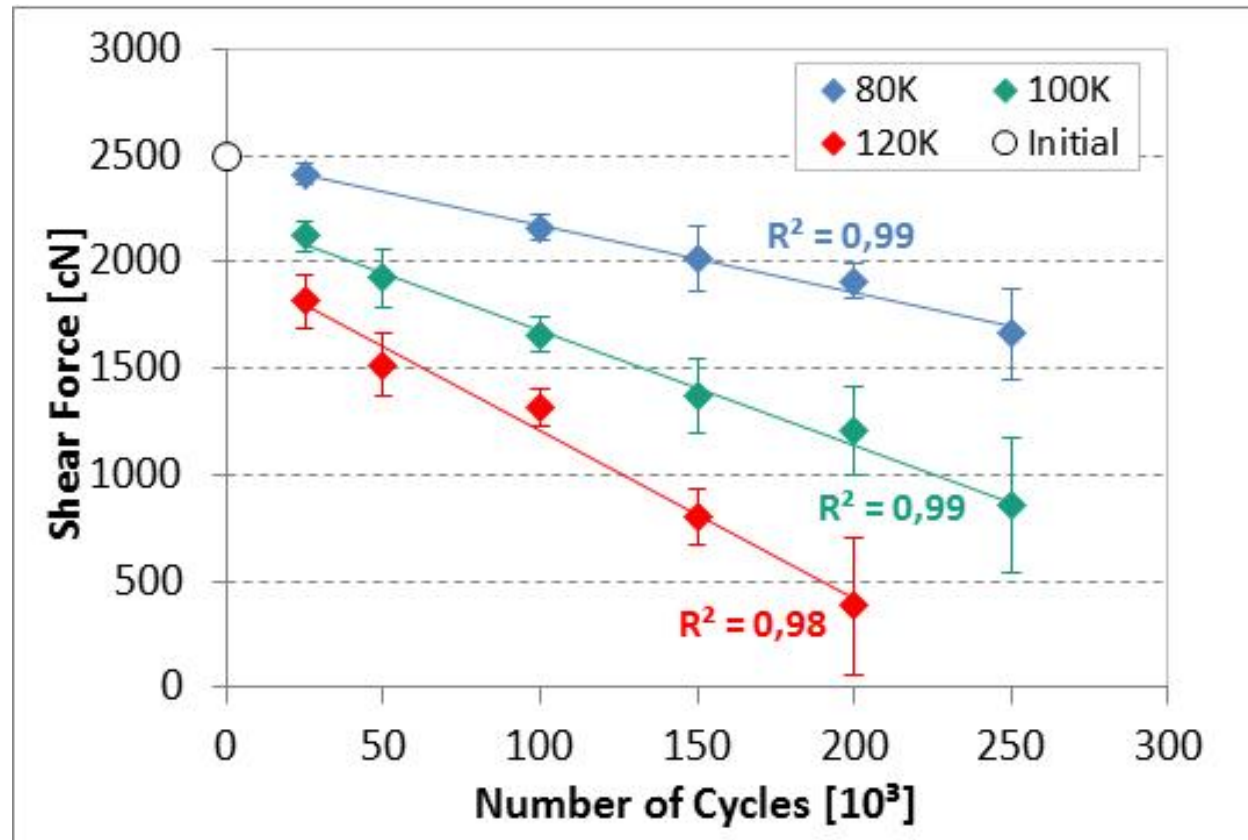


→ Individual temperature swing for each bond!



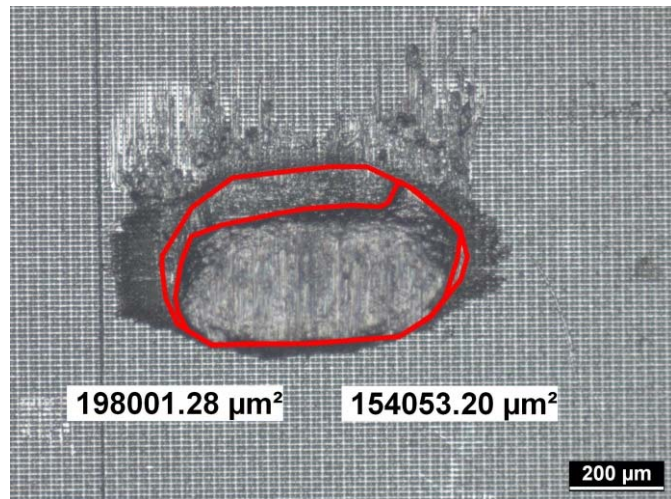
# Results of Power Cycling

## Shear Force - high US-power (Q1)

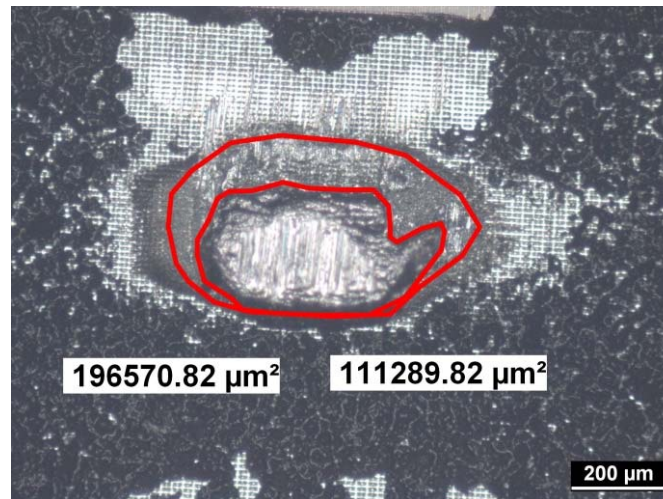
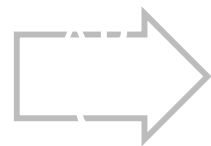


- Decreasing shear force with increasing number of cycles
- Higher  $\Delta T$  lead to higher degradation rate

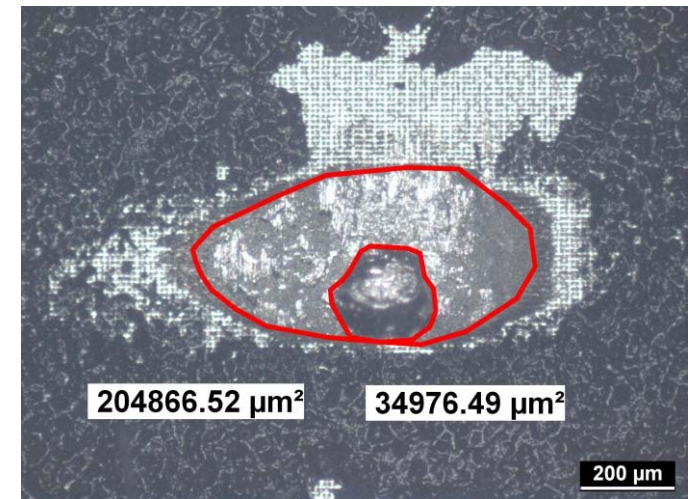
# Estimation of Crack Length



Initial



100.000 Zyklen

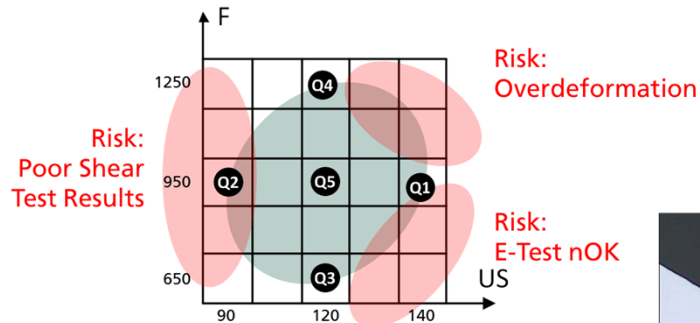


200.000 Zyklen

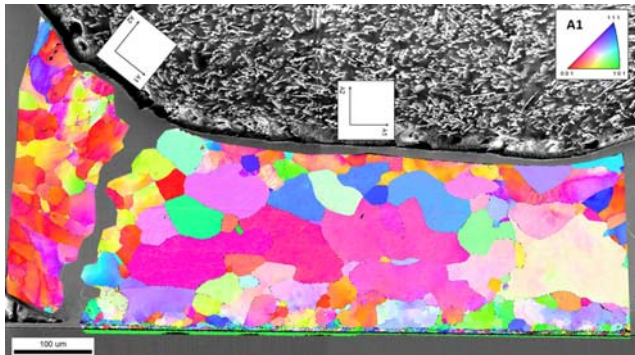


# Lifetime Testing and Modelling for Wire Bonds in Power

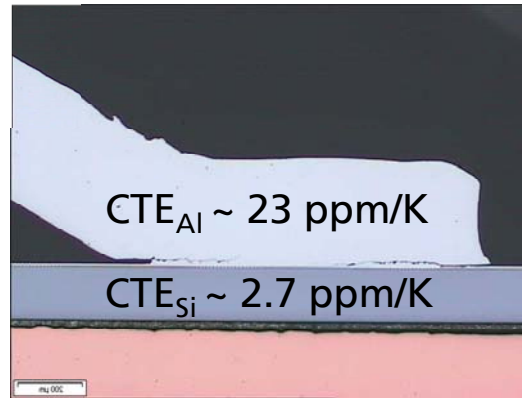
## Bonding Process



## Microstructure



EBSD image after 2000 cycles

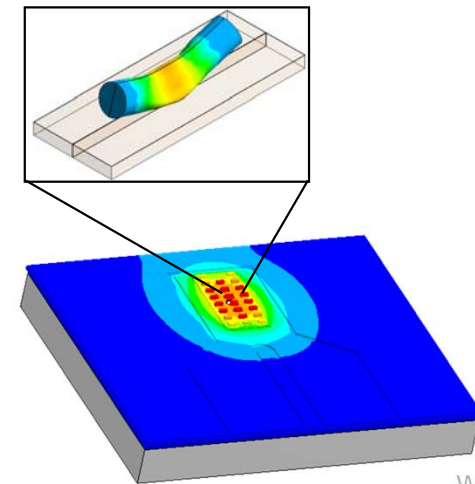


Material Data

## Advanced Lifetime Test



## FEM based Lifetime Model

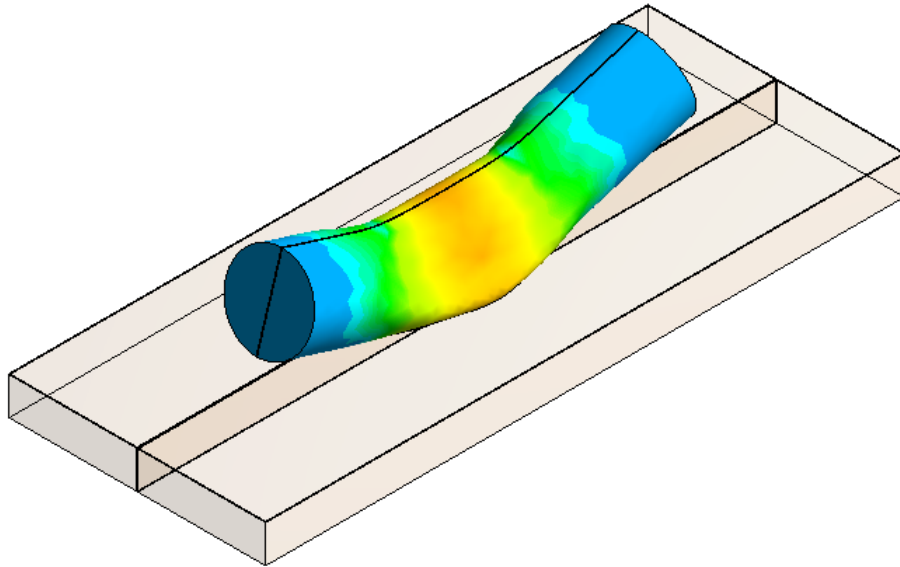


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Wittler et al.



# LIFETIME MODELLING

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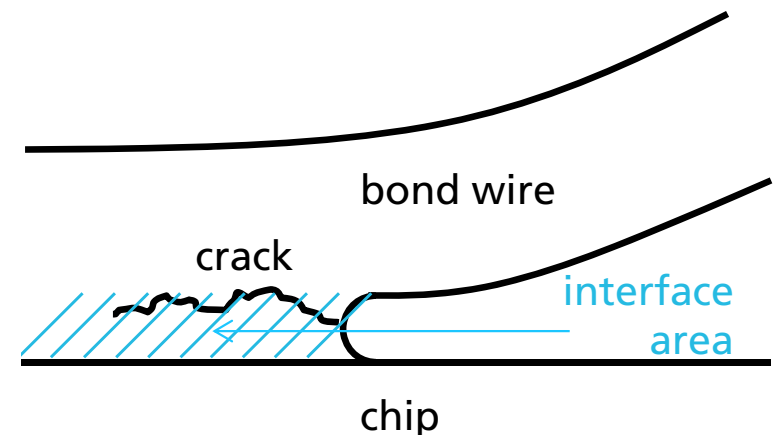
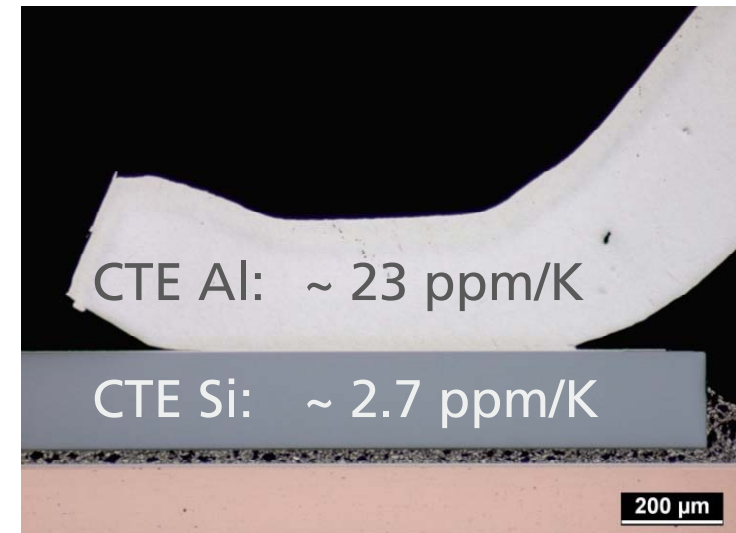
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# Crack Driving Force

- Temperature difference causes strains in materials

$$\varepsilon_{th} = \alpha_{CTE} \cdot \Delta T$$

- High stresses occur due to different CTEs of adjacent materials
- Plastic deformation during temperature cycling causes fatigue damage in aluminum
- Loop shape and relative movement of bond wedges have only negligible influence



# Lifetime Modelling Approach

- Widest spread among POF approaches is Coffin Manson approach

$$N_f = C_1 (\Delta \varepsilon_{pl})^{-C_2}$$

- Crack growth approach comprises interesting advantages:

Modified Paris law:

$$\boxed{\frac{dA}{dN}} = C_1 (\Delta \varepsilon_{pl})^{C_2}$$

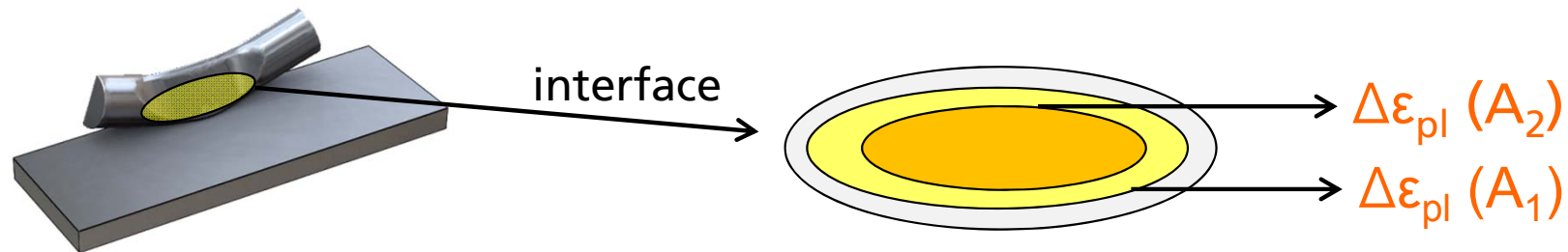
- Validity is independent of interface area
- Crack-length dependency of damage parameter is taken into account
- Damage accumulation can be considered by stepwise integration

# Lifetime Modelling Approach – Workflow

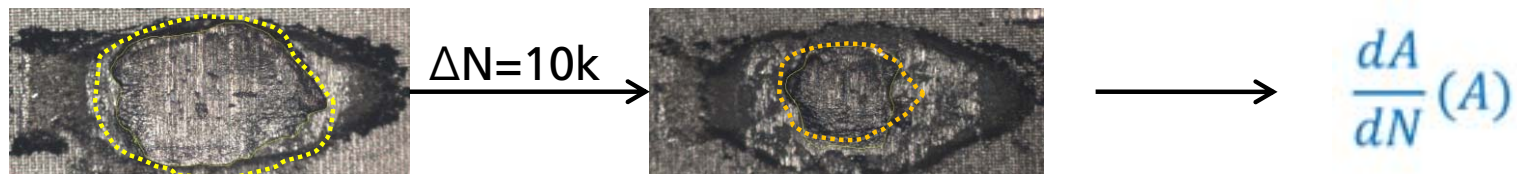
- Goal: Lifetime from integration of crack growth law

$$\frac{dA}{dN}(A) = C_1 [\Delta \varepsilon_{pl}(A)]^{C_2} \longrightarrow N = \int_{A_0}^{A_f} \frac{1}{C_1 [\Delta \varepsilon_{pl}(A)]^{C_2}} dA$$

- For a set of crack states the damage parameter is calculated

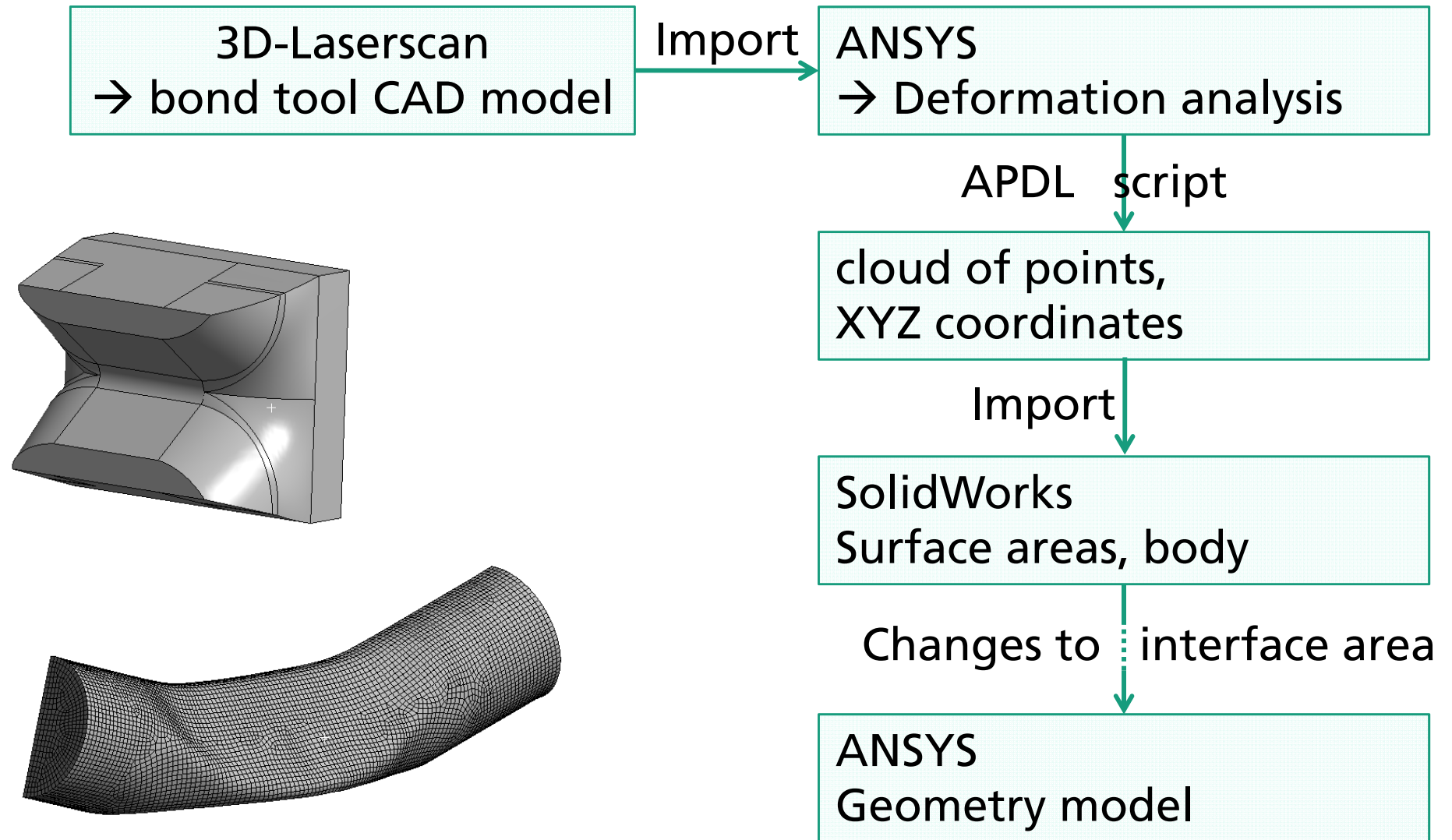


- Crack propagation rate is obtained from experiments



- Parameters  $C_1$  and  $C_2$  can be fitted

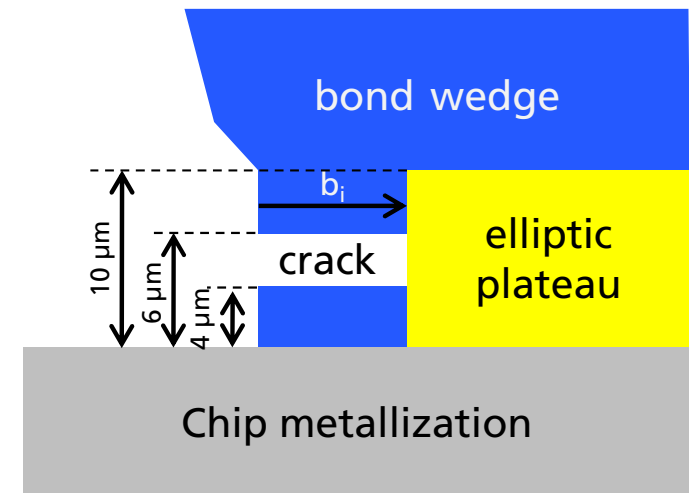
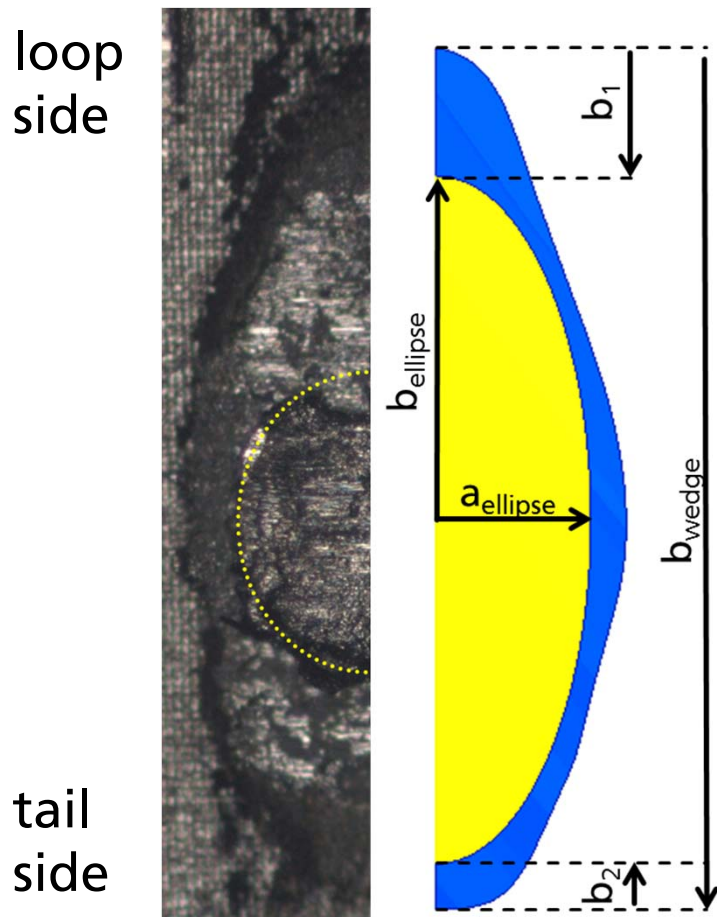
# Building the Geometry Model





# Modelling of Crack States

- Crack is modelled as 2  $\mu\text{m}$  gap, centred 5  $\mu\text{m}$  above the chip



- The uncracked area is modelled elliptically
- Ellipse is defined by its length, width and position derived from shear pictures
- Parametric crack generation in dependence of  $b_2$  (distance tail side)

# Evaluation of an Adequate Damage Parameter

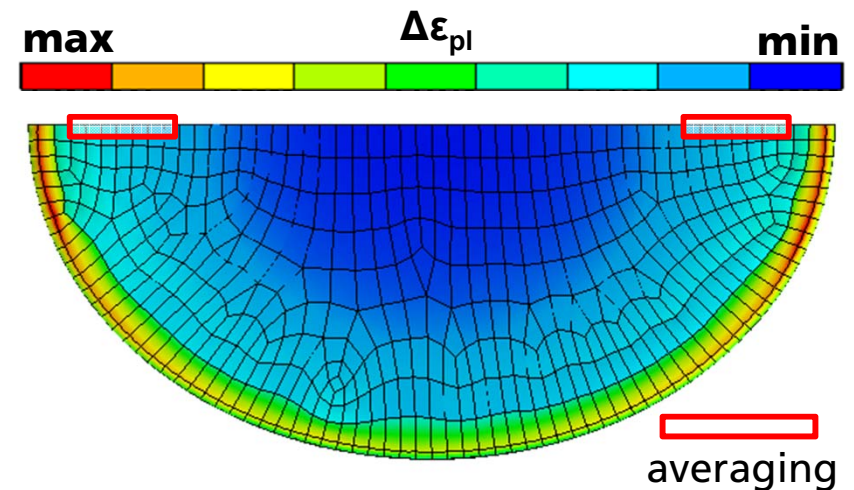
- Accumulated plastic strain is representative for damage in the aluminium

$$\frac{dA}{dN} = C1(\Delta\epsilon_{pl, acc})^{C2}$$

- singularities at the crack front are mesh dependent,

→  $\Delta\epsilon_{pl, acc}$  will be averaged over a volume

- length b is characteristic for cracked area and elliptic geometry  
→ a volume of the crack path along b is selected



- the increase in accumulated strains is evaluated from 3<sup>rd</sup> to 4<sup>th</sup> cycle, no change in  $\Delta\epsilon_{pl, acc}$  after the 4<sup>th</sup> cycle

$$\Delta\epsilon_{pl, acc} = \epsilon_{pl, acc, 4} - \epsilon_{pl, acc, 3}$$

Grams et al., EUROSIM 2014

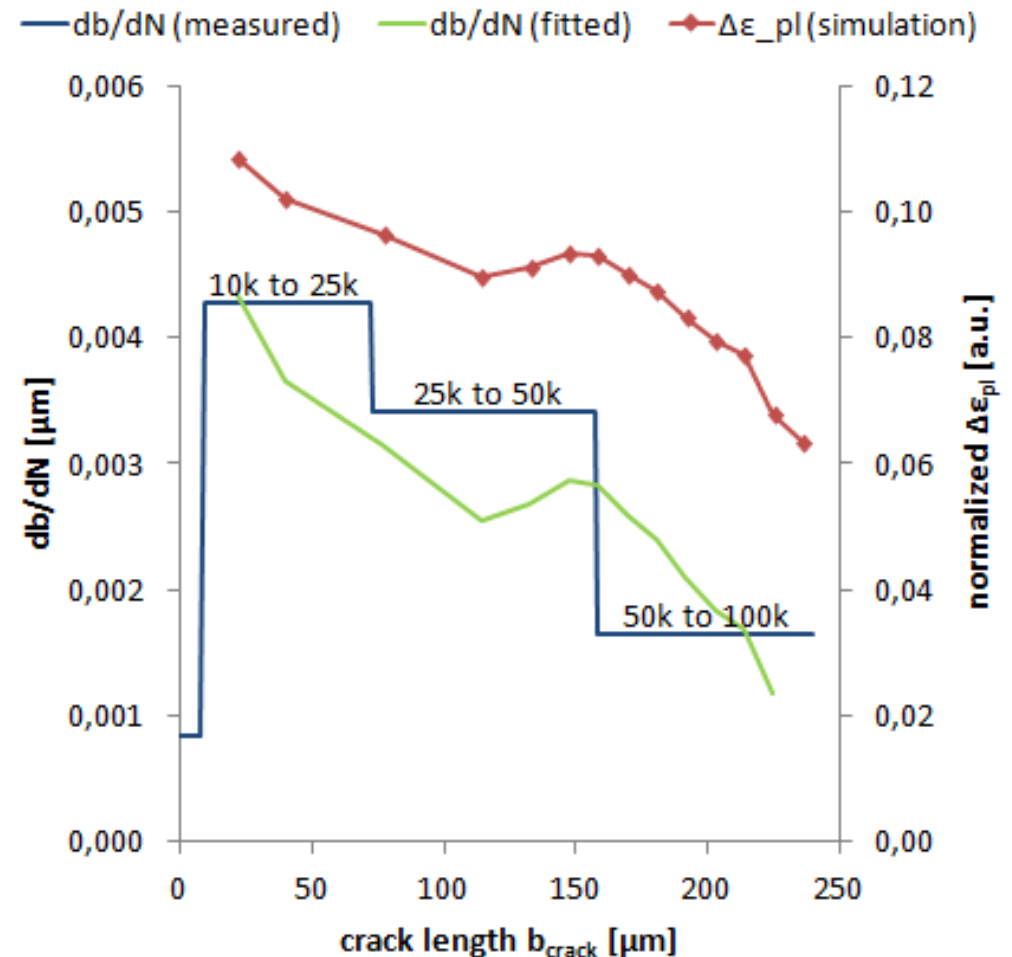


# Adjusting the Fit Parameters

- with the collected  $db/dN$  data and the calculated  $\Delta\varepsilon_{pl}$ , fit parameters can be determined

$$\frac{db}{dN}(b) = C_1[\Delta\varepsilon_{pl}(b)]^{C_2}$$

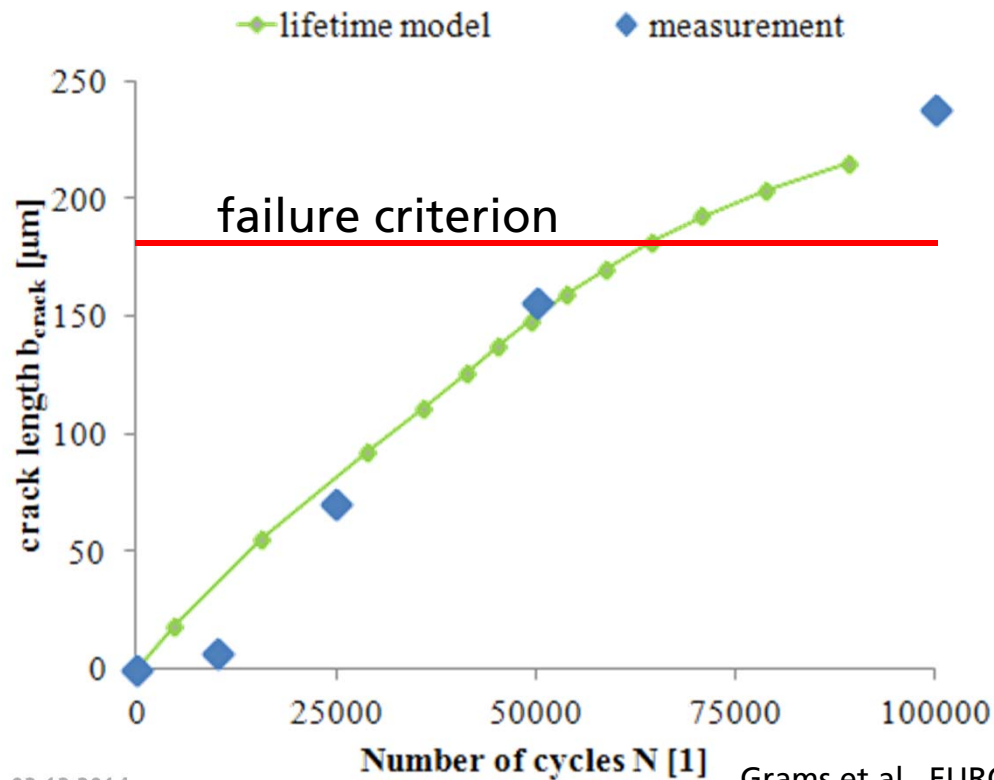
- the early state ( $N < 10k$ ) of slow crack initiation cannot be described by the approach
- after crack initiation the measured data can be fitted well



# Calculation of Crack Length

- With the crack growth law now also crack lengths can be calculated

$$\frac{dA}{dN}(A) = C_1 [\Delta \varepsilon_{pl}(A)]^{C_2} \longrightarrow N = \int_{A_0}^{A_f} \frac{1}{C_1 [\Delta \varepsilon_{pl}(A)]^{C_2}} dA$$



- Crack length results from the integration of the  $db/dN$ -fit
- Failure criterion can be chosen, e.g.

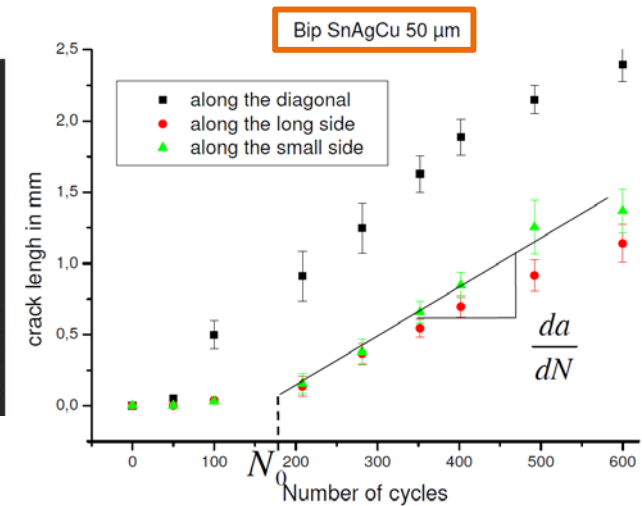
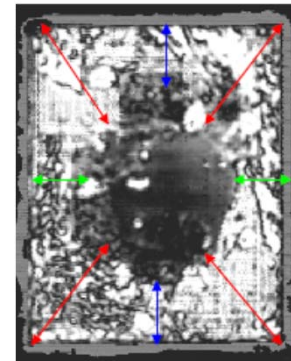
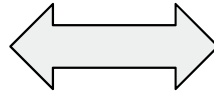
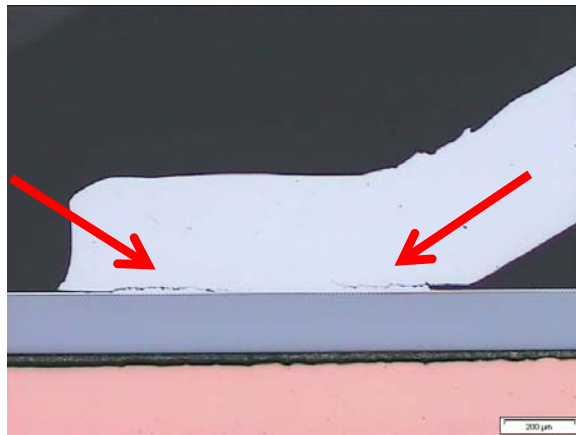
$$A_{interface} < A_{wire}$$

# Summary

- A modelling approach exists to analyse complex load histories by consideration of **interaction of failure mechanisms** and **nonlinearity in damage superposition**
- A unified damage model for Al wire bonds was developed based on
  - ... a special power cycling test
  - ... a finite element model describing the damage progression and geometrical influences
- Data can be extracted in a simplified form for a damage parameter used in a thermal coupling model.

# Outlook

## ■ Coupling of Die Attach and Wire Bond degradation



(S. Deplanque et al., EuroSimE 2006)

## ■ Analysis of typical mission profiles

■ ...

# Thank you for your attention !

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This support is gratefully acknowledged.